

Motivation for additional electron temperature diagnostic

The most common electron temperature diagnostics, Thomson Scattering (TS) and Electron Cyclotron Emission (ECE), both require large diagnostic footprints and expensive optics.

Another electron temperature diagnostic is the Pulse-Height-Analysis (PHA) system, which derives the electron temperature from the x-ray bremsstrahlung continuum [1,2]. However, the main disadvantage of the PHA method is poor temporal resolution of the Si(Li) diode detectors [1].

X-ray pinhole camera uses a pixilated Pilatus detector that allows single photon counting at a rate 1MHz per pixel and the setting of energy thresholds [3, 4].

The detector configuration is optimized by Shannon-sampling theory [5], such that spatial profiles of the x-ray continuum intensity can be obtained simultaneously for different energies.

The exponential-like dependence of the x-ray intensity with photon energies is compared with a model describing the Be filter, attenuation in air, and detector efficiency, as well as different sets of energy thresholds [6].

Method for detecting and counting X-Rays and setting different energy thresholds.

The number of X-rays detected from the Dectris photodiode is given by the density and temperature expression below. Where C is a constant n_e is electron density, Z_{eff} is the effective charge of the plasma.

 $I_{x-ray} \propto \frac{Cn_e^2 Z_{eff}}{T^{1/2}} \int_0^\infty \frac{exp(-E/T_e)}{E} Tr^{Be} Tr^{Air} Ab^{Si} S_{Detector} dE$

The transmission terms inside the integral, Tr, can be approximated with an exponential, while the Si absorption is formulated from Tr + Ab = 1 so Ab = 1-Tr.

> $E_0 = (2Nr_0hc\tau k^2)^{1/3} = (ln2)^{1/3}E_{C,50\%}$ $Tr^{x} \approx exp(E_{0}^{3}/E^{3})$

The E₀ term is formulated based on the thickness and atomic density of the material in addition to an energy scaling factor k [4, 6]. In practice we relate this to the photon energy where the material transmits 50% of the incoming photons, $E_{C,50\%}$ [3. 4].

In addition we account for the electrical response of the detector which is fitted with an error function and an E_0 term used in the transmission calculation [10]. $S_{Detector} = \frac{1}{2} \left(1 + erfc(E_0^3/E^3) \right)$

The detector works by exciting a potential difference across each pixel when it is struck by a photon. If the potential difference is greater than the threshold voltage, the photon is counted [3].



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Ar Spectra

0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 v104

NSTX-L

으 0.6는

2D pixelated

Aperture

+ Be 50 μm foil

SXR detector

Bottom .

T_{e0} [keV]

1.0

0.5

10

Time (s)



To isolate the continuum emissions, we are concerned with picking an energy window which avoids impurity lines. The most common impurities in C-Mod are Molybdenum from the plasma facing components and Argon (trace amounts) which is used for diagnostic purposes [7, 9]. The energy thresholds are set between 4 eV and 16 keV, at 1 keV intervals, where Mo and Ar are line free.



Lines for temperatures ranging from 1 keV to 10 keV show that the emissions for Ar and Mo are line free in the energy region of interests [11]. Temperature profiles are given by I \ Vertical view spacing and repeating the different energy thresholds along the height of the detector [7, 8]. Different channels of the detector report the emissions from different parts of the plasma.

Measurements are integrated along the line of sight of the detector such that the emissivity is a report of the average conditions along that line. This reports the inner plasma conditions in cases where density and temperature drop off rapidly at the plasma edge.



Time (s)

Brightness intensities are measured (line integrated) on each channel (inset plots b and c) for the duration of the plasma shot at C-Mod [7].

The decay of intensities as a function of energy can be resolved for each "energy channel" of the detectors.

Primary times of interest are before and during the ion cyclotron resonance heating (ICRH, highlighted in red).

We calculate electron temperature before, during and after transitions between low (L) and high (H) confinement modes present.

The results for electron temperature are plotted against each other over the duration of the shot.

1.5

 $\frac{I_{x-ray_{thresh}} - I_{x-ray_{threshmax}}}{I_{x-ray_{threshmax}}} \propto \int_{0}^{\infty} \frac{exp(-E/T_e)}{E} Tr^{Be} Tr^{Air} Ab^{Si} S_{Detector} dE$

1.0

Time (s)

1.5

0.5

Intensities were recorded with 20 ms exposure times to ensure counts high enough at all energies to be statistically relevant.

The parameter determining the rate of decay of x-ray intensity determines the electron temperature for each fit.

The numeric fit captures the physics of the x-ray transmission as photons reach the detector. The numeric fit temperatures are compared against ECE and TS.





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measurements can be

$$B_i = \sum_j L_{ij} E_j, \qquad E_i = \sum_j L_{ji}^{-1} B_i$$

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